imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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SURFACE MOUNT DISPLAY

Part Number: ACDA04-41SEKWA-F01

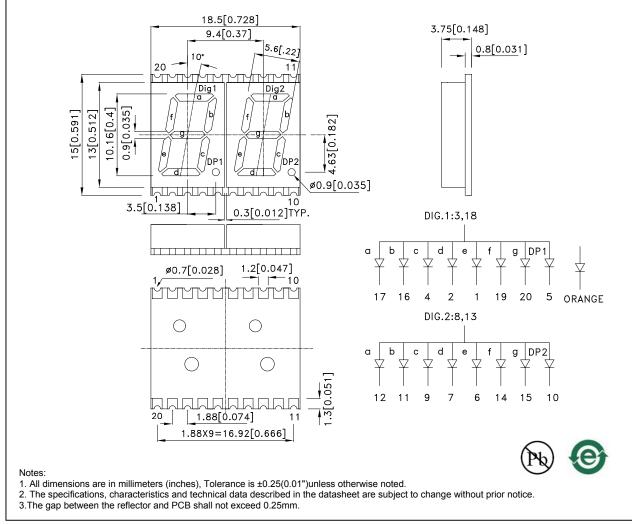
Super Bright Orange

Features

- 0.4 inch digit height.
- Low current operation.
- Excellent character appearance.
- Mechanically rugged.
- Gray face, white segment.
- Package: 250pcs/ reel.
- Moisture sensitivity level : level 2a.
- RoHS compliant.

Description

The Super Bright Orange device is made with AlGaInP (on GaAs substrate) light emitting diode chip.



Package Dimensions& Internal Circuit Diagram

SPEC NO: DSAG0239 APPROVED: WYNEC REV NO: V.9A CHECKED: Joe Lee DATE: NOV/09/2011 DRAWN: Y.H.Wu PAGE: 1 OF 5 ERP: 1352000320

	Selection Guide										
	Part No.	Dice	Lens Type	lv (ucd) [1] @ 10mA		Description					
				Min.	Тур.	Decemption					
	ACDA04-41SEKWA-F01	Super Bright Orange (AlGaInP)	White Diffused	21000	60000	Common Anode, Rt.					
				*9000	*15000	Hand Decimal.					

Note:

1. Luminous intensity/ luminous Flux: +/-15%.

*Luminous intensity value is traceable to the CIE127-2007 compliant national standards.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Orange	610		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Orange	601		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Orange	29		nm	IF=20mA
С	Capacitance	Super Bright Orange	15		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Orange	2.1	2.5	V	I⊧=20mA
lr	Reverse Current	Super Bright Orange		10	uA	Vr=5V

Notes:

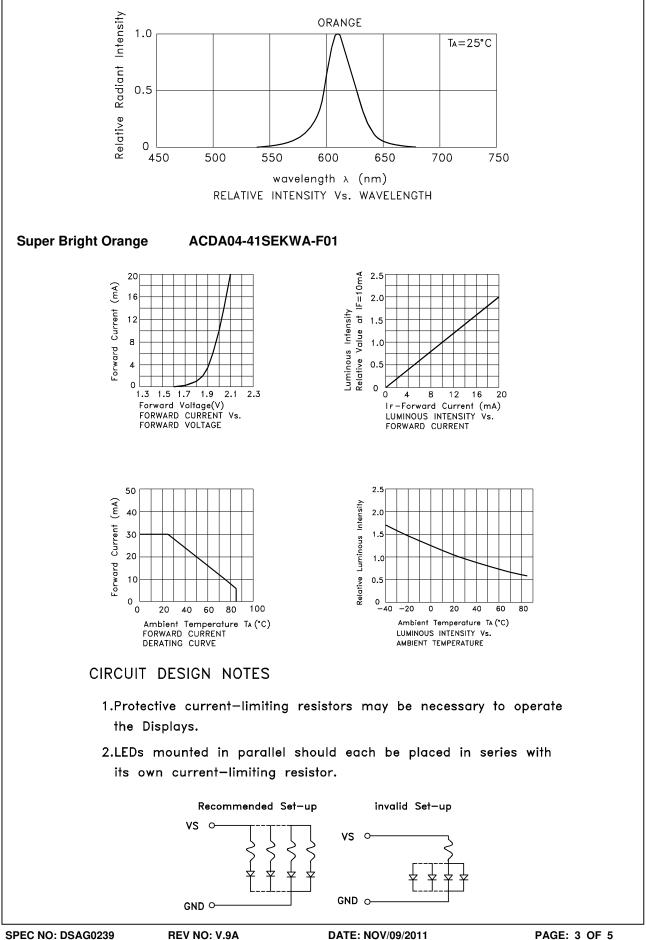
Wavelength: +/-1nm.
Forward Voltage: +/-0.1V.
Wavelength value is traceable to the CIE127-2007 compliant national standards.

Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange	Units
Power dissipation	75	mW
DC Forward Current	30	mA
Peak Forward Current [1]	195	mA
Reverse Voltage	5	V
Operating / Storage Temperature	-40°C To +85°C	

Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.



APPROVED: WYNEC

CHECKED: Joe Lee

DRAWN: Y.H.Wu

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